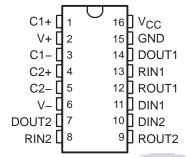
SLLS410I - JANUARY 2000 - REVISED JANUARY 2004

- RS-232 Bus-Pin ESD Protection Exceeds ±15 kV Using Human-Body Model (HBM)
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates With 3-V to 5.5-V V<sub>CC</sub> Supply
- Operates Up To 250 kbit/s
- Two Drivers and Two Receivers
- Low Supply Current . . . 300 μA Typical
- External Capacitors . . . 4 × 0.1 μF
- Accepts 5-V Logic Input With 3.3-V Supply
- Alternative High-Speed Pin-Compatible Device (1 Mbit/s)
  - SNx5C3232
- Applications
  - Battery-Powered Systems, PDAs, Notebooks, Laptops, Palmtop PCs, and Hand-Held Equipment

### D, DB, DW, OR PW PACKAGE (TOP VIEW)



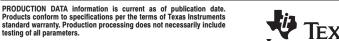
### description/ordering information

### **ORDERING INFORMATION**

TA	PACKAGI	≣†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	2010 (5)	Tube of 40	MAX3232CD	
	SOIC (D)	Reel of 2500	MAX3232CDR	MAX3232C
J	0010 (DW)	Tube of 40	MAX3232CDW	MANAGOOO
000 1: 7000	SOIC (DW)	Reel of 2000	MAX3232CDWR	MAX3232C
−0°C to 70°C	CCOD (DD)	Tube of 80	MAX3232CDB	MA3232C
	SSOP (DB)	Reel of 2000	MAX3232CDBR	WA3232C
on and the	TOCOD (DWA	Tube of 90	MAX3232CPW	L 1 4 4 2 2 2 2 2 2
	TSSOP (PW)	Reel of 2000	MAX3232CPWR	MA3232C
	0010 (D)	Tube of 40	MAX3232ID	MANAGOOD
	SOIC (D)	Reel of 2500	MAX3232IDR	MAX3232I
	COIC (DW)	Tube of 40	MAX3232IDW	MAX3232I
–40°C to 85°C	SOIC (DW)	Reel of 2000	MAX3232IDWR	IVIAA32321
-40°C to 85°C	CCOD (DD)	Tube of 80	MAX3232IDB	MB3232I
	SSOP (DB)	Reel of 2000	MAX3232IDBR	NB32321
	TCCOD (DW)	Tube of 90	MAX3232IPW	MB3232I
	TSSOP (PW) Reel of 2000		MAX3232IPWR	IVIDOZOZI

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.







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SLLS410I – JANUARY 2000 – REVISED JANUARY 2004

### description/ordering information (continued)

The MAX3232 device consists of two line drivers, two line receivers, and a dual charge-pump circuit with ±15-kV ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The devices operate at data signaling rates up to 250 kbit/s and a maximum of 30-V/µs driver output slew rate.

#### **Function Tables**

### **EACH DRIVER**

INPUT DIN	OUTPUT DOUT
L	Н
Н	L

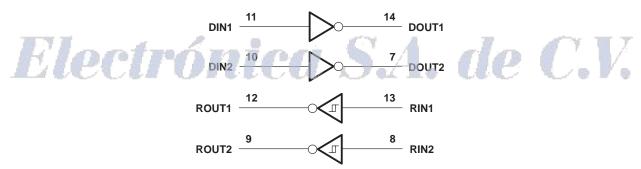
H = high level, L = low level

### **EACH RECEIVER**

RIN	ROUT ROUT
L	Н
Н	L
Open	Н

H = high level, L = low level, Open = input disconnected connected driver off

### logic diagram (positive logic)



SLLS410I – JANUARY 2000 – REVISED JANUARY 2004

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub> (see Note 1)	0.3 V to 6 V
Positive output supply voltage range, V+ (see Note 1)	0.3 V to 7 V
Negative output supply voltage range, V- (see Note 1)	0.3 V to –7 V
Supply voltage difference, V+ – V– (see Note 1)	13 V
Input voltage range, V <sub>I</sub> : Drivers	0.3 V to 6 V
Receivers	
Output voltage range, V <sub>O</sub> : Drivers	13.2 V to 13.2 V
Receivers	0.3 V to V <sub>CC</sub> + 0.3 V
Package thermal impedance, $\theta_{JA}$ (see Notes 2 and 3):	: D package 73°C/W
	DB package 82°C/W
	DW package 57°C/W
	PW package108°C/W
Operating virtual junction temperature, T <sub>J</sub>	
Storage temperature range, T <sub>stg</sub>	65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to network GND.

- 2. Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.

### recommended operating conditions (see Note 4 and Figure 4)

			MIN	NOM	MAX	UNIT
	0 1 1	V <sub>CC</sub> = 3.3 V	3	3.3	3.6	.,
	Supply voltage	V <sub>CC</sub> = 5 V	4.5	5	5.5	V
M	Data ship land bear to the se	V <sub>CC</sub> = 3.3 V	2		10	٧
VIH	Driver high-level input voltage	V <sub>C</sub> C = 5 V	2.4			V
VIL	Driver low-level input voltage	DIN			0.8	V
	Driver input voltage	DIN	0		5.5	<b>V</b>
VI	Receiver input voltage		-25	7	25	V
	Operating free air temperature	MAX3232C	0	2 lm	70	°C
TA	Operating free-air temperature	MAX3232I	-40		85	-0

NOTE 4: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V.

### electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 4)

PARAMETER		TEST CONDITIONS		MIN	TYP‡	MAX	UNIT
ICC	Supply current	No load,	V <sub>CC</sub> = 3.3 V or 5 V		0.3	1	mA

<sup>‡</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$  or  $V_{CC} = 5 \text{ V}$ , and  $T_A = 25^{\circ}\text{C}$ .

NOTE 4: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.



### MAX3232 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER

WITH ±15-kV ESD PROTECTION SLLS410I – JANUARY 2000 – REVISED JANUARY 2004

### **DRIVER SECTION**

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 4)

	PARAMETER	TEST CONDITIONS			TYP†	MAX	UNIT
Vон	High-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GND,	DIN = GND	5	5.4		V
VOL	Low-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GND,	$DIN = V_{CC}$	-5	-5.4		V
lιΗ	High-level input current	VI = VCC			±0.01	±1	μΑ
IIL	Low-level input current	V <sub>I</sub> at GND			±0.01	±1	μΑ
la at	Chart singuit autout aumant	V <sub>CC</sub> = 3.6 V,	VO = 0 V		105		A
IOS <sup>‡</sup> Short-circuit output current		$V_{CC} = 5.5 \text{ V},$ $V_{O} = 0 \text{ V}$			±35	±60	mA
r <sub>O</sub>	Output resistance	$V_{CC}$ , V+, and V- = 0 V,	$V_O = \pm 2 V$	300	10M		Ω

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$  or  $V_{CC} = 5 \text{ V}$ , and  $T_A = 25^{\circ}\text{C}$ .

NOTE 4: Test conditions are C1–C4 = 0.1  $\mu$ F at  $V_{CC}$  = 3.3  $\vee$  ± 0.3  $\vee$ ; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at  $V_{CC}$  = 5  $\vee$  ± 0.5  $\vee$ .

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 4)

	PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
	Maximum data rate	C <sub>L</sub> = 1000 pF, One DOUT switching,	$R_L = 3 kΩ$ , See Figure 1	150	250		kbit/s
tsk(p)	Pulse skew§	C <sub>L</sub> = 150 pF to 2500 pF	R <sub>L</sub> = 3 kΩ to 7 kΩ, See Figure 2		300		ns
CD(tri)	Slew rate, transition region	$R_L = 3 k\Omega \text{ to } 7 k\Omega$	C <sub>L</sub> = 150 pF to 1000 pF	6		30	V/us
SR(tr)	(see Figure 1)	V <sub>CC</sub> = 3.3 V	C <sub>L</sub> = 150 pF to 2500 pF	4		30	ν/μ5

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$  or  $V_{CC} = 5 \text{ V}$ , and  $T_A = 25^{\circ}\text{C}$ .

NOTE 4: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.

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<sup>‡</sup> Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

<sup>§</sup> Pulse skew is defined as |tpLH - tpHL| of each channel of the same device.

SLLS410I – JANUARY 2000 – REVISED JANUARY 2004

### RECEIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 4)

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>†</sup>	MAX	UNIT
Vон	High-level output voltage	I <sub>OH</sub> = -1 mA	V <sub>CC</sub> -0.6V	V <sub>CC</sub> -0.1 V		V
VOL	Low-level output voltage	I <sub>OL</sub> = 1.6 mA			0.4	V
V 5	V <sub>CC</sub> = 3.3 V		1.5	2.4		
V <sub>IT+</sub>	Positive-going input threshold voltage	V <sub>CC</sub> = 5 V		1.8	2.4	V
.,	N	V <sub>CC</sub> = 3.3 V	0.6	1.2		.,
$V_{IT-}$	Negative-going input threshold voltage	V <sub>CC</sub> = 5 V	0.8	1.5		V
V <sub>hys</sub>	Input hysteresis (V <sub>IT+</sub> – V <sub>IT</sub> –)			0.3		V
rį	Input resistance	$V_{ } = \pm 3 \text{ V to } \pm 25 \text{ V}$	3	5	7	kΩ

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$  or  $V_{CC} = 5 \text{ V}$ , and  $T_A = 25^{\circ}\text{C}$ .

NOTE 4: Test conditions are C1–C4 = 0.1  $\mu$ F at  $V_{CC}$  = 3.3  $V \pm 0.3$  V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at  $V_{CC}$  = 5  $V \pm 0.5$  V.

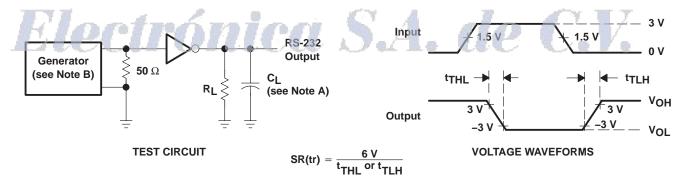
### switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 3)

	PARAMETER	TEST CONDITIONS	MIN TYP <sup>†</sup> MAX	UNIT
tPLH	Propagation delay time, low- to high-level output	0. 450.5	300	ns
tPHL	Propagation delay time, high- to low-level output	C <sub>L</sub> = 150 pF	300	ns
tsk(p)	Pulse skew <sup>‡</sup>	4	300	ns

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC}$  = 3.3 V or  $V_{CC}$  = 5 V, and  $T_A$  = 25°C.

NOTE 4: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_O = 50~\Omega$ , 50% duty cycle,  $t_\Gamma \le 10$  ns.  $t_f \le 10$  ns.

Figure 1. Driver Slew Rate

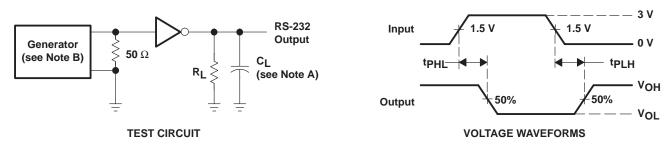
<sup>‡</sup> Pulse skew is defined as |tplh - tphl| of each channel of the same device.

### MAX3232

### 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH $\pm$ 15-kV ESD PROTECTION

SLLS410I – JANUARY 2000 – REVISED JANUARY 2004

### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_O = 50 \Omega$ , 50% duty cycle,  $t_r \le 10$  ns.

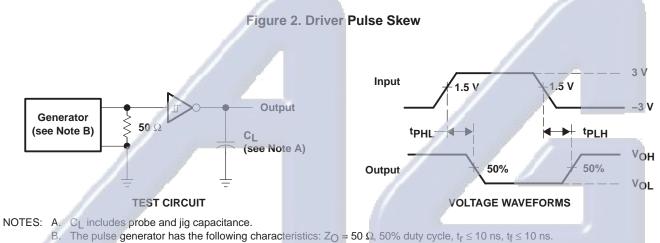
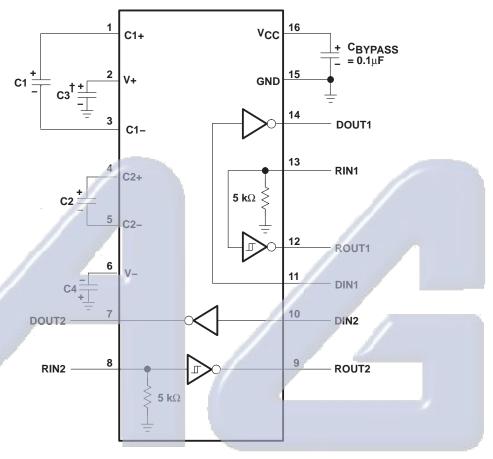


Figure 3. Receiver Propagation Delay Times

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SLLS410I – JANUARY 2000 – REVISED JANUARY 2004

### **APPLICATION INFORMATION**



†C3 can be connected to VCC or GND.

NOTES: A. Resistor values shown are nominal.

B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

### VCC vs CAPACITOR VALUES

VCC	C1	C2, C3, C4		
3.3 V ± 0.3 V 5 V ± 0.5 V 3 V to 5.5 V	0.1 μF 0.047 μF 0.1 μF	0.1 μF 0.33 μF 0.47 μF		

Figure 4. Typical Operating Circuit and Capacitor Values

### PACKAGE OPTION ADDENDUM



4-Mar-2005

### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)
MAX3232CD	ACTIVE	SOIC	D	16	40	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
MAX3232CDB	ACTIVE	SSOP	DB	16	80	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
MAX3232CDBR	ACTIVE	SSOP	DB	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
MAX3232CDR	ACTIVE	SOIC	D	16	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
MAX3232CDW	ACTIVE	SOIC	DW	16	40	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
MAX3232CDWR	ACTIVE	SOIC	DW	16	2000	Pb-Free (RoHS)	CÚ NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
MAX3232CPW	ACTIVE	TSSOP	PW	16	90	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
MAX3232CPWR	ACTIVE	TSSOP	PW	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
MAX3232ID	ACTIVE	SOIC	D	16	40	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
MAX3232IDB	ACTIVE	SSOP	DB	16	80	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
MAX3232IDBR	ACTIVE	SSOP	DB	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
MAX3232IDR	ACTIVE	SOIC	D	16	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
MAX3232IDW	ACTIVE	SOIC	DW	16	40	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
MAX3232IDWR	ACTIVE	SOIC	DW	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
MAX3232IPW	ACTIVE	TSSOP	PW	16	90	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
MAX3232IPWR	ACTIVE	TSSOP	PW	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM

<sup>&</sup>lt;sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

None: Not yet available Lead (Pb-Free).

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

Addendum-Page 1

<sup>(2)</sup> Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

### PACKAGE OPTION ADDENDUM



4-Mar-2005

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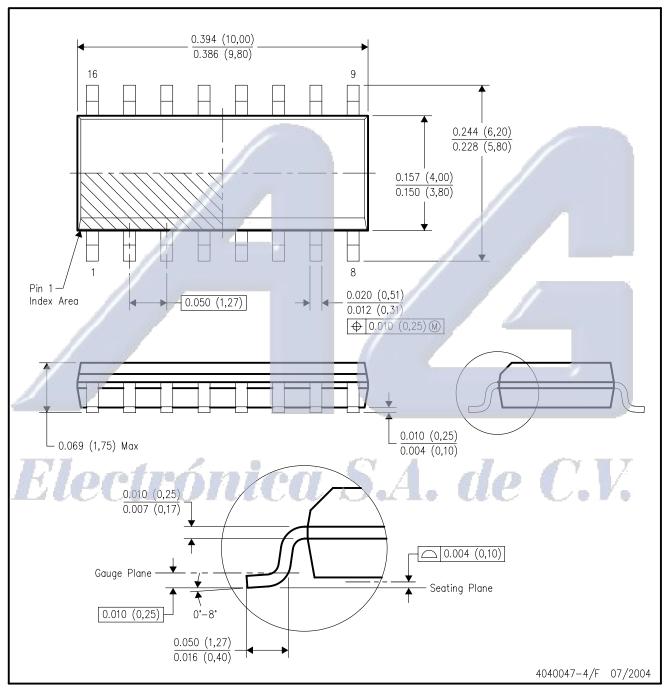
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### **MECHANICAL DATA**

### D (R-PDSO-G16)

### PLASTIC SMALL-OUTLINE PACKAGE



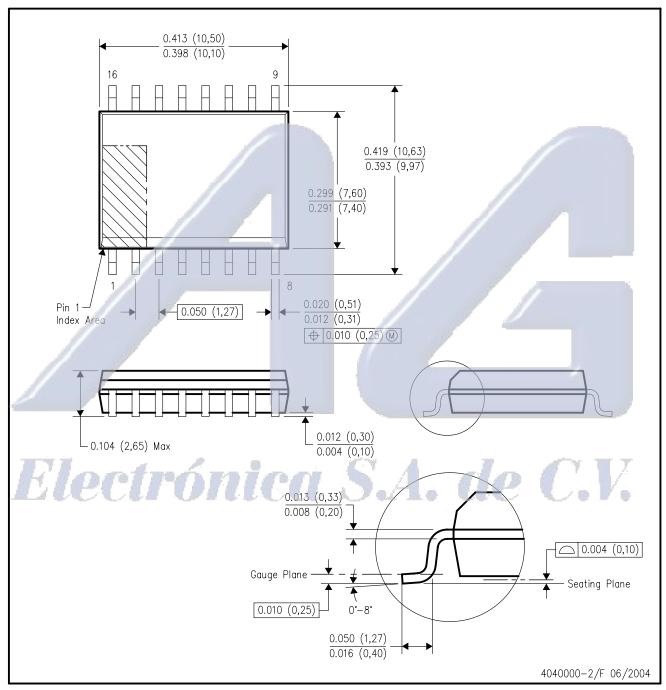
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AC.



### DW (R-PDSO-G16)

### PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AA.

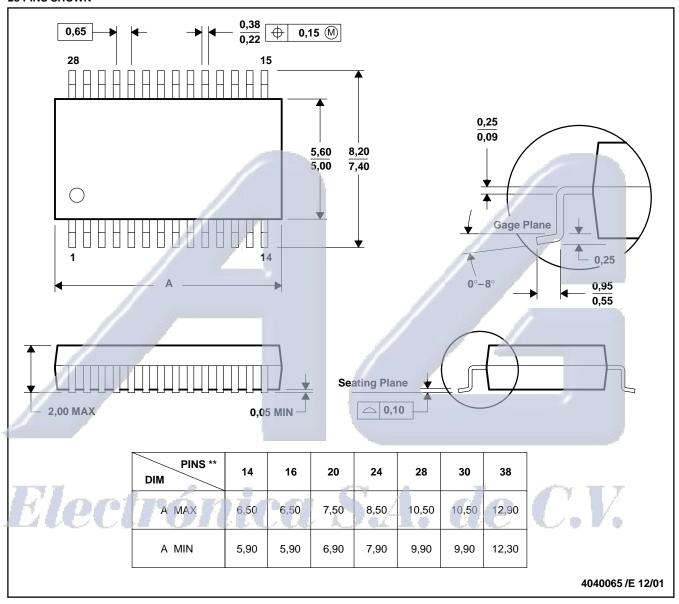


MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

### DB (R-PDSO-G\*\*)

### PLASTIC SMALL-OUTLINE

### **28 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

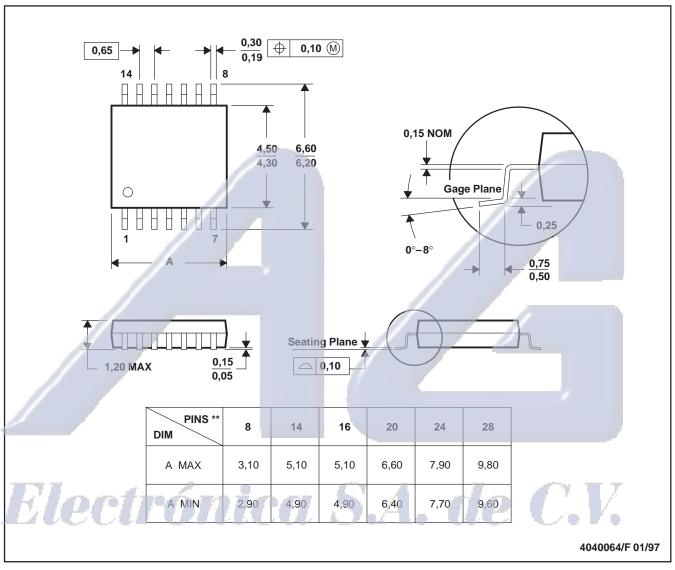
D. Falls within JEDEC MO-150

MTSS001C - JANUARY 1995 - REVISED FEBRUARY 1999

### PW (R-PDSO-G\*\*)

### 14 PINS SHOWN

### PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153